



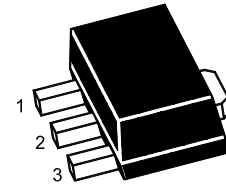
BCX51,BCX52,BCX53 TRANSISTOR (PNP) SOT-89 Plastic-Encapsulate Transistors

FEATURES

- NPN Complements to BCX54,BCX55,BCX56
- Low Voltage
- High Current

APPLICATIONS

- Medium Power General Purposes
- Driver Stages of Audio Amplifiers



1.Base 2.Collector 3.Emitter
SOT-89 Plastic Package

MARKING:BCX51:AA, BCX51-10:AC, BCX51-16:AD
BCX52:AE, BCX52-10:AG, BCX52-16:AM
BCX53:A H, BCX53-10:AK, BCX53-16:AL

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter		Value	Unit
V_{CBO}	Collector-Base Voltage	BCX51	-45	V
		BCX52	-60	
		BCX53	-100	
V_{CEO}	Collector-Emitter Voltage	BCX51	-45	V
		BCX52	-60	
		BCX53	-80	
V_{EBO}	Emitter-Base Voltage		-5	V
I_C	Collector Current		-1	A
P_C	Collector Power Dissipation		500	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient		250	$^{\circ}\text{C/W}$
T_j	Junction Temperature		150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature		-55~+150	$^{\circ}\text{C}$

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ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-100\mu\text{A}, I_E=0$	BCX51	-45		V
			BCX52	-60		
			BCX53	-100		
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=-10\text{mA}, I_B=0$	BCX51	-45		V
			BCX52	-60		
			BCX53	-80		
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-100\mu\text{A}, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB}=-30\text{V}, I_E=0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$			-0.1	μA
DC current gain	$h_{FE(1)}^*$	$V_{CE}=-2\text{V}, I_C=-5\text{mA}$	63			
	$h_{FE(2)}^*$	$V_{CE}=-2\text{V}, I_C=-150\text{mA}$	63		250	
	$h_{FE(3)}^*$	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}^*$	$I_C=-0.5\text{A}, I_B=-50\text{mA}$			-0.5	V
Base -emitter voltage	V_{BE}^*	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$			-1	V
Transition frequency	f_T	$V_{CE}=-5\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$		50		MHz

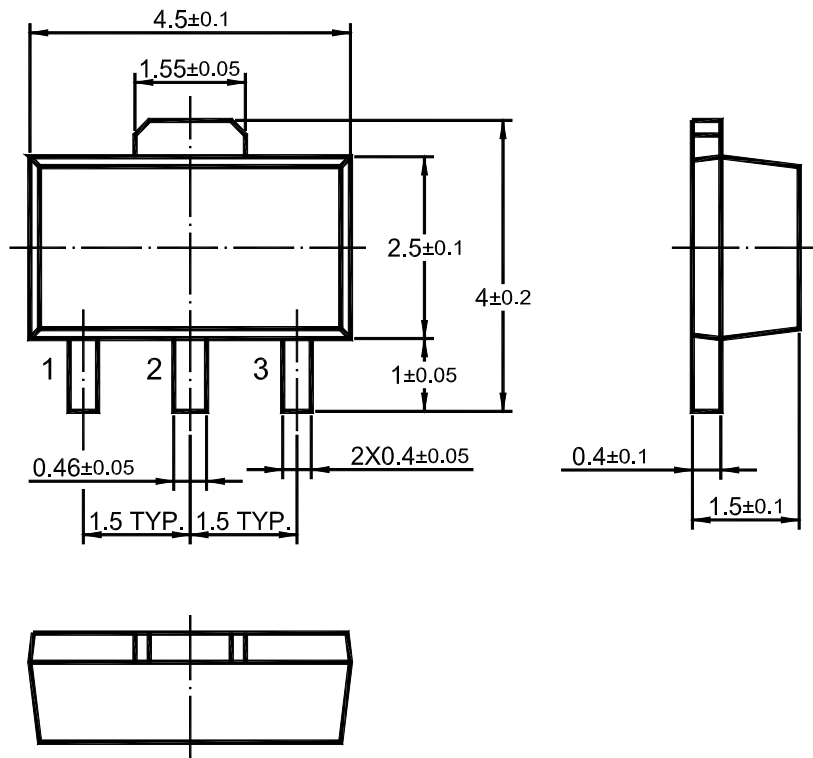
* Pulse Test

CLASSIFICATION OF $h_{FE(2)}$

RANK	BCX51 BCX52 BCX53	BCX51-10 BCX52-10 BCX53-10	BCX51-16 BCX52-16 BCX53-16
RANGE	63–250	63–160	100–250

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SOT-89 PACKAGE OUTLINE



Dimensions in mm